

## Typical Applications

The HMC574MS8 / HMC574MS8E is ideal for:

- Cellular/3G Infrastructure
- Private Mobile Radio Handsets
- WLAN, WiMAX \& WiBro
- Automotive Telematics
- Test Equipment


## Functional Diagram



## Features

Low Insertion Loss: 0.3 dB
High Third Order Intercept: +65 dBm
Isolation: 30 dB
Single Positive Supply: +3 to +8 V
SMT Package: MSOP8
Included in the HMC-DK005 Designer's Kit

## General Description

The HMC574MS8 \& HMC574MS8E are low-cost SPDT switches in 8 -lead MSOP packages for use in transmit/receive applications which require very low distortion at high incident power levels. The device can control signals from DC to 3 GHz and is especially suited for Cellular/3G infrastructure, WiMAX and WiBro applications with only 0.3 dB typical insertion loss. The design provides 5 watt power handling performance and +65 dBm third order intercept at +8 Volt bias. RF1 and RF2 are reflective shorts when "Off".

## Electrical Specifications,

$T_{A}=+25^{\circ} \mathrm{C}, \mathrm{Vctl}=0 /+5 \mathrm{Vdc}, \mathrm{Vdd}=+5 \mathrm{Vdc}$ (Unless Otherwise Stated), 50 Ohm System

| Parameter | Frequency | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Insertion Loss | $\begin{aligned} & \text { DC }-1.0 \mathrm{GHz} \\ & \mathrm{DC}-2.0 \mathrm{GHz} \\ & \mathrm{DC}-2.5 \mathrm{GHz} \\ & \mathrm{DC}-3.0 \mathrm{GHz} \end{aligned}$ |  | $\begin{gathered} \hline 0.25 \\ 0.3 \\ 0.4 \\ 0.5 \\ \hline \end{gathered}$ | $\begin{aligned} & 0.5 \\ & 0.6 \\ & 0.7 \\ & 0.8 \end{aligned}$ | $\begin{aligned} & \hline \mathrm{dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ |
| Isolation | $\begin{aligned} & \text { DC }-1.0 \mathrm{GHz} \\ & \text { DC }-2.0 \mathrm{GHz} \\ & \text { DC }-2.5 \mathrm{GHz} \\ & \mathrm{DC}-3.0 \mathrm{GHz} \end{aligned}$ | $\begin{aligned} & 26 \\ & 24 \\ & 21 \\ & 16 \end{aligned}$ | $\begin{aligned} & 30 \\ & 28 \\ & 25 \\ & 20 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB |
| Return Loss | $\begin{aligned} & \text { DC }-1.0 \mathrm{GHz} \\ & \mathrm{DC}-2.0 \mathrm{GHz} \\ & \mathrm{DC}-2.5 \mathrm{GHz} \\ & \mathrm{DC}-3.0 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 35 \\ & 25 \\ & 18 \\ & 16 \\ & \hline \end{aligned}$ |  | dB <br> dB <br> dB <br> dB |
| $\begin{array}{ll}\text { Input Power for 1dB Compression } & \mathrm{Vctl}=0 /+3 \mathrm{~V} \\ \mathrm{VctI}=0 /+5 \mathrm{~V} \\ \mathrm{Vctl}=0 /+8 \mathrm{~V}\end{array}$ | $0.5-3.0 \mathrm{GHz}$ | $\begin{aligned} & 33 \\ & 35 \\ & 37 \end{aligned}$ | $\begin{aligned} & 36 \\ & 38 \\ & 39 \\ & \hline \end{aligned}$ |  | dBm dBm dBm |
| Input Third Order Intercept $\mathrm{Vctl}=0 /+3 \mathrm{~V}$ <br> (Two-tone Input Power $=+27 \mathrm{dBm}$ Each Tone) $\mathrm{Vctl}=0 /+5 \mathrm{~V}$ <br> $\mathrm{Vctl}=0 /+8 \mathrm{~V}$  | $0.5-3.0 \mathrm{GHz}$ |  | $\begin{aligned} & 55 \\ & 63 \\ & 65 \end{aligned}$ |  | dBm dBm dBm |
| Switching Characteristics <br> tRISE, tFALL (10/90\% RF) tON, tOFF (50\% CTL to 10/90\% RF) | DC - 3.0 GHz |  | $\begin{gathered} 80 \\ 120 \end{gathered}$ |  | $\begin{aligned} & \mathrm{ns} \\ & \mathrm{~ns} \end{aligned}$ |

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## Insertion Loss



RF1 to RF2 Isolation


## Input P0.1dB vs. Vdd



Isolation Between RFC \& RF1/RF2


## Return Loss



## Input P1dB vs. Vdd




Input IP3 vs. Input Power @ 900 MHz


Input Third Order Intercept


2nd \& 3rd Harmonics @ 900 MHz
Vdd $=+5$ Volts


Input IP3 vs. Input Power @ 1900 MHz


2nd \& 3rd Harmonics @ 900 MHz Vdd = +3 Volts


2nd \& 3rd Harmonics @ 900 MHz Vdd $=+8$ Volts



Input P0.1dB vs. Vdd


| Max. Input Power $V_{d d}=0 /+8 \mathrm{~V}$ | 0.5-2.5 GHz | 39 dBm |
| :---: | :---: | :---: |
| Bias Voltage Range (Vdd) |  | -0.2 to +10 Vdc |
| Control Voltage Range (A \& B) |  | -0.2 to +Vdd Vdc |
| Hot Switching Power Level$V_{d d}=+8 \mathrm{~V}$ |  | 39 dBm |
| Channel Temperature |  | $150{ }^{\circ} \mathrm{C}$ |
| Continuous Pdiss ( $\mathrm{T}=+85^{\circ} \mathrm{C}$ ) (derate $10 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $85^{\circ} \mathrm{C}$ ) |  | 0.65W |
| Thermal Resistance |  | $100^{\circ} \mathrm{C} / \mathrm{W}$ |
| Storage Temperature |  | -65 to $+150^{\circ} \mathrm{C}$ |
| Operating Temperature |  | -40 to $+85^{\circ} \mathrm{C}$ |
| ESD Sensitivity (HBM) |  | Class 1A |

DC Blocks are required at ports RFC, RF1 and RF2

ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Input P1dB vs. Vdd


Bias Voltage \& Current

| Vdd (Vdc) | Typical Idd $(\mu \mathrm{A})$ |
| :---: | :---: |
| +3 | 2 |
| +5 | 10 |
| +8 | 40 |

Control Voltages

| State | Bias Condition |
| :--- | :--- |
| Low | 0 to +0.2 Vdc @ $10 \mu \mathrm{~A}$ Typical |
| High | Vdd $\pm 0.2 \mathrm{Vdc} @ 10 \mu \mathrm{~A}$ Typical |

## Truth Table

| Control Input (Vctl) |  | Signal Path State |  |
| :---: | :---: | :---: | :---: |
| A | B | RFC to RF1 | RFC to RF2 |
| High | Low | Off | On |
| Low | High | On | Off |

## Outline Drawing



## Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking ${ }^{[3]}$ |
| :---: | :---: | :---: | :---: | :---: |
| HMC574MS8 | Low Stress Injection Molded Plastic | Sn/Pb Solder | MSL1 ${ }^{[1]}$ | H574 <br> XXXX |
| HMC574MS8E | RoHS-compliant Low Stress Injection Molded Plastic | $100 \%$ matte Sn | MSL1 ${ }^{[2]}$ | $\underline{\text { H574 }}$ |

[1] Max peak reflow temperature of $235^{\circ} \mathrm{C}$
[2] Max peak reflow temperature of $260^{\circ} \mathrm{C}$
[3] 4-Digit lot number XXXX

## Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
| :---: | :---: | :---: | :---: |
| 1 | A | See truth table and control voltage table. |  |
| 2 | B | See truth table and control voltage table. |  |
| $3,5,8$ | RFC, RF1, RF2 | This pin is DC coupled and matched to 50 Ohm. <br> Blocking capacitors are required. |  |
| 6,7 | Gdd | This pin must be connected to RF/DC ground. |  |

## Typical Application Circuit



Notes:

1. Set logic gate and switch $\mathrm{Vdd}=+3 \mathrm{~V}$ to +5 V and use HCT series logic to provide a TTL driver interface.
2. Control inputs $\mathrm{A} / \mathrm{B}$ can be driven directly with CMOS logic $(\mathrm{HC})$ with Vdd of +3 to +8 Volts applied to the CMOS logic gates and to pin 4 of the RF switch.
3. DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
4. Highest RF signal power capability is achieved with Vdd set to +8 V . The switch will operate properly (but at lower RF power capability) at bias voltages down to +3 V .

## Evaluation Circuit Board

RoHS $\sqrt{ }$


## List of Materials for Evaluation PCB $104124{ }^{[1]}$

| Item | Description |
| :--- | :--- |
| J1 - J3 | PCB Mount SMA RF Connector |
| J4 - J7 | DC Pin |
| C1 - C3 | 100 pF capacitor, 0402 Pkg. |
| C4 | $10,000 \mathrm{pF}$ capacitor, 0603 Pkg. |
| R1, R2 | 100 Ohm resistor, 0402 Pkg. |
| U1 | HMC574MS8 / HMC574MS8E T/R Switch |
| PCB [2] | 104122 Evaluation PCB |

[1] Reference this number when ordering complete evaluation PCB
[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

RoHS $\sqrt{ }$


Notes:

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